PCN Number:	20180	0180425000.1			PC	PCN Date: July 20 2018			
Title: Qualification of a new Bump Site plus addition of Polyimide for select devices									
Customer Contact:	PCN Mar	nager	Dept:	Quality Serv	vices				
Proposed 1 st Ship Da	ite: Oc	Oct 20 2018 Estimated Sar Availability:						Provided upon Request	
Change Type:									
Assembly Site		, , , , , , , , , , , , , , , , , , , ,			Assembly Materials				
Design		Electrical S	•		Mechanical Specification			ecification	
Test Site		Packing/Sh			4	Test Proce			
Wafer Bump Site		Wafer Bum			4	Wafer Bun			
Wafer Fab Site		Wafer Fab				Wafer Fab	Pro	cess	
		Part number							
D 1 11 6 61			PCN De	etaiis					
Description of Chang	je:								
introduction of Polyimide:		Current			New				
Wafer Bump Si	ite	HBUMP			DBUMP				
Die Coating		None		Polyimide					
· · · · · · · · · · · · · · · · · · ·									
Reason for Change:									
Reason for Change: HBUMP facility has clos	ed								
		orm, Funct	ion, Qu	ality or Relia	abil	ity (positi	ve ,	/ negative):	
HBUMP facility has clos		orm, Funct	ion, Qu	ality or Relia	abil	ity (positi	ve ,	/ negative):	
HBUMP facility has clos Anticipated impact o	n Fit, F	·		ality or Relia	abil	ity (positi	ve ,	/ negative):	
HBUMP facility has clos Anticipated impact o None	on Fit, F	Material Deproduction release. U	ation eclaration data ar Jpon pro	ons or Product nd will be avai duction releas	: Co llabl	ntent repor	ts a	are driven from	
HBUMP facility has closs Anticipated impact of None Anticipated impact of No Impact to the	on Fit, F	Material Deproduction release. Upobtained fi	ation eclaratic data ar Jpon pro rom the	ons or Product nd will be avai duction releas TI ECO websi	: Co llabl se tl	ntent repor	ts a	are driven from	
HBUMP facility has closs Anticipated impact o None Anticipated impact o I No Impact to the Material Declaration	on Fit, F	Material Deproduction release. Upobtained fi	ation eclaratic data ar Jpon pro rom the	ons or Product nd will be avai duction releas TI ECO websi	: Co llabl se tl	ntent repor	ts a	are driven from	

Product Affected							
TPS650001RTER	TPS650003RTET	TPS650007RTER	TPS65000RTER	Ì			
TPS650001RTET	TPS650006RTER	TPS650007RTET	TPS65000RTET	Ì			
TPS650003RTER	TPS650006RTET						



Qualification Report

TPS65000RTER Bump site offload from HBUMP to DBUMP for Commercial Devices Approve Date 12-Jul-2018

Product Attributes

Attributes	Qual Device: TP\$65000RTER	QBS Product Reference: <u>TPS57114QRTERDN</u>	QB\$ Process Reference: <u>TP\$55340QPWPRQ1</u>	QB\$ Package Reference: <u>\$N0701013DRC</u>	QB\$ Package Reference: TPA6040A4RHB
Assembly Site	MLA (TIM)	TIM	TAI	MLA	MLA
Package Family	QFN, 3 X 3 (MM)	WQFN	HTSSOP	SON	QFN
Flammability Rating	-	UL 94 V-0	UL 94 V-0	UL94-V0	UL94-V0
Wafer Fab Supplier	MIHO	MIHO	MIHO	MIHO	MIHO
Wafer Process	LBC7	LBC7	LBC7	LBC7	LBC7

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: TPS65000RTER	QBS Product Reference: <u>TPS57114QRTERDN</u>	QBS Process Reference: <u>TPS55340QPWPRQ1</u>	QBS Package Reference: <u>SN0701013DRC</u>	QBS Package Reference: TPA6040A4RHB
AC	Autoclave 121C	96 Hours	-	3/231/0	3/231/0	3/231/0	3/231/0
ED	Electrical Distributions	Cpk>1.67 Room, Hot, & Cold	-	1/90/0	1/30/0	-	-
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	3/2400/0	-	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	-
HBM	ESD - HBM	4000 V	-	1/12/0	-	=	-
CDM	ESD - CDM	1500 V	-	1/3/0	-	=	-
HTOL	Life Test, 125C	1000 Hours	-	3/231/0	3/231/0	-	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	-	-	3/231/0	3/231/0
HTSL	High Temp. Storage Bake, 175C	500 Hours	-	1/50/0	-		-
HTSL	High Temp. Storage Bake, 150C	1000 Hours	-	-	1/50/0		-
LU	Latch-up	(per JESD78)	-	1/6/0	1/6/0	-	-
TC	Temperature Cycle, -65/150C	500 Cycles	1/77/0	3/231/0	3/231/0	3/231/0	3/231/0
TS	Thermal Shock, -65/150C	1000 cycles	-	-	-	-	3/231/0
	Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours						
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/tk Hours, and 170C/20 Hours, a 170C/30 Hours, and 170C/20							
Qualified Pb-Free(SMT) and Green							

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com

⁻ QBS: Qual By Similarity - Qual Device TPS65000RTER is qualified at LEVEL2-260CG